

# Demonstration Board EPC9101

## Quick Start Guide

*EPC2014 + EPC2015 1 MHz Buck Converter*



## DESCRIPTION

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The EPC9101 demonstration board is a 1.2 V output, 1 MHz buck converter with an 20 A maximum output current and 8 V to 24 V input voltage range. The demonstration board features the EPC2014 and EPC2015 enhancement mode (*eGaN*<sup>®</sup>) field effect transistors (FETs), as well as the first *eGaN* FET specific integrated circuit driver – the Texas Instruments LM5113. The EPC9101 board is not intended as a reference design, but to showcase the performance that can be achieved using the *eGaN* FETs and *eGaN* driver together.

The EPC9101 demonstration board is 3" square and contains a fully closed loop buck converter. The power stage is a single sided design and is contained within 20mm x 11mm area and includes driver, *eGaN* FETs, bus capacitors and output inductor.

There are also various probe points to facilitate simple waveform measurement and efficiency calculation. A complete block diagram of the circuit is given in Figure 1. For more information on the EPC2014/5 *eGaN* FETs or LM5113 driver, please refer to the datasheet available from EPC at [www.epc-co.com](http://www.epc-co.com) and [www.ti.com](http://www.ti.com). These datasheets, as well that of the LT3833 controller should be read in conjunction with this quick start guide.

**Table 1: Performance Summary (TA = 25°C)**

| SYMBOL           | PARAMETER                  | CONDITIONS                                  | MIN | TYP  | MAX | UNITS |
|------------------|----------------------------|---|-----|------|-----|-------|
| V <sub>IN</sub>  | Bus Input Voltage Range    |   | 8   |      | 24  | V     |
| V <sub>OUT</sub> | Switch Node Output Voltage |   |     | 1.2  |     | V     |
| I <sub>OUT</sub> | Switch Node Output Current |   |     |      | 20* | A     |
| f <sub>SW</sub>  | Switching frequency        |   |     | 1000 |     | kHz   |
|                  | Peak Efficiency            | 12 V <sub>INr</sub> = 10 A I <sub>OUT</sub> |     | 89.5 |     | %     |
|                  | Full Load Efficiency       | 12 V <sub>INr</sub> = 20 A I <sub>OUT</sub> |     | 86.4 |     | %     |
|                  | Full Load Efficiency       | 24 V <sub>INr</sub> = 20 A I <sub>OUT</sub> |     | 83.3 |     | %     |

\*Maximum limited by thermal considerations and requires 200 LFM forced air cooling

## Quick Start Procedure

Demonstration board EPC9101 is easy to set up to evaluate the performance of the EPC2014 and EPC2015 *eGaN* FETs and LM5113 driver. Refer to Figure 2 for proper connect and measurement setup and follow the procedure below:

1. With power off, connect the input power supply bus between  $V_{IN}$  and GND banana jacks as shown.
2. With power off, connect the active (constant current) load as desired between  $V_{OUT}$  and GND banana jacks as shown.
3. Turn on the supply voltage to the required value (do not exceed the absolute maximum voltage of 24 V on  $V_{IN}$ ).
4. Measure the output voltage to make sure the board is fully functional and operating no-load.
5. Turn on active load to the desired load current while staying below the maximum current (20 A)
6. Once operational, adjust the bus voltage and load current within the allowed operating range and observe the output switching behavior, efficiency and other parameters.
7. For shutdown, please follow steps in reverse.

NOTE. When measuring the high frequency content switch node of gate voltage, care must be taken to avoid long ground leads. Measure these by placing the oscilloscope probe tip on the top pad of D3 and grounding the probe directly across D3 on the bottom pad provided for switch node and using the bottom pad of R20 and the GND pad below it for gate voltage. See Figure 3 for proper scope probe technique. Measuring the switch node with a high bandwidth ( $\geq 500\text{MHz}$ ) probe and high bandwidth scope ( $\geq 1\text{GHz}$ ) is recommended.

NOTE. The dead-times for both the leading and trailing edges have been set for optimum full load efficiency. Adjustment is not recommended, but can be done at own risk by replacing R21 and R22 with potentiometers P1 and P2. This should be done while monitoring both the input current and switch-node voltage to determine the effect of these adjustments. Under no circumstance should the input pins to the LM5113 be probed during operation as the added probe capacitance will change the device timing.

## CIRCUIT PERFORMANCE

The EPC9101 demonstration circuit was designed to showcase the size and performance that can readily be achieved at 1 MHz operation using *eGaN* FETs for supply voltages up to 24V or more. Since a closed loop controller is included on board, the associated losses must also be lumped into any efficiency measurement that is performed. It is possible to supply a separate regulated 5V supply to the EXTVCC pin to further improve efficiency. In that case, the controller and gate drive losses are still included, but the associated conversion loss from the input supply (LDO loss) is removed.

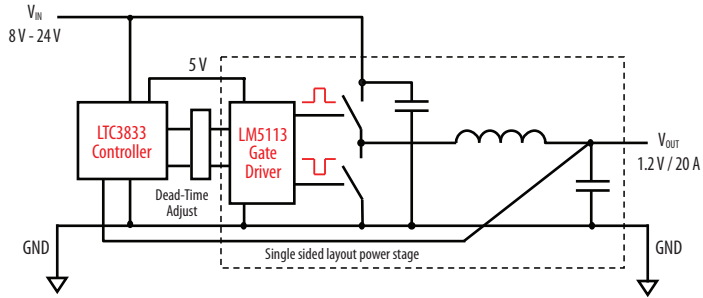


Figure 1: Block Diagram of EPC9101 Demonstration Board

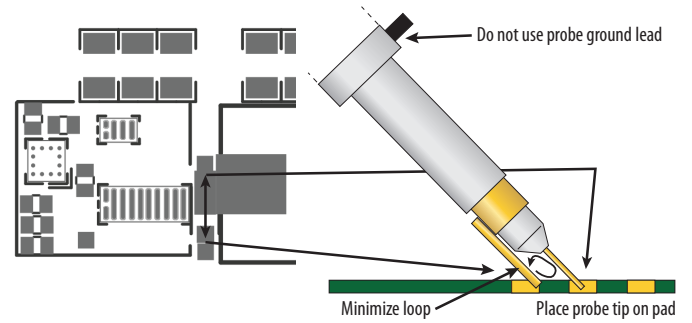


Figure 3: Proper Measurement of Switch Node or Gate Voltage

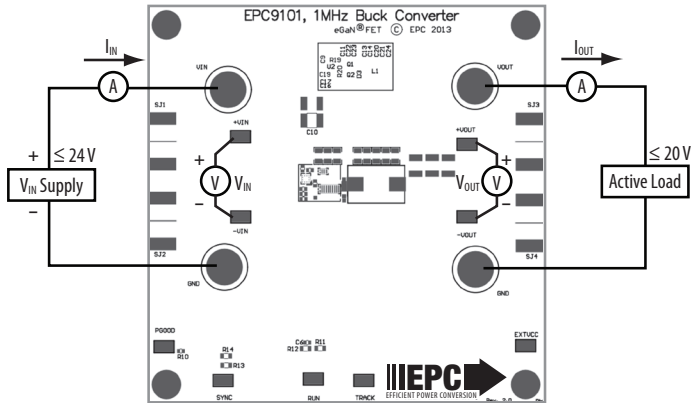


Figure 2: Proper Connection and Measurement Setup

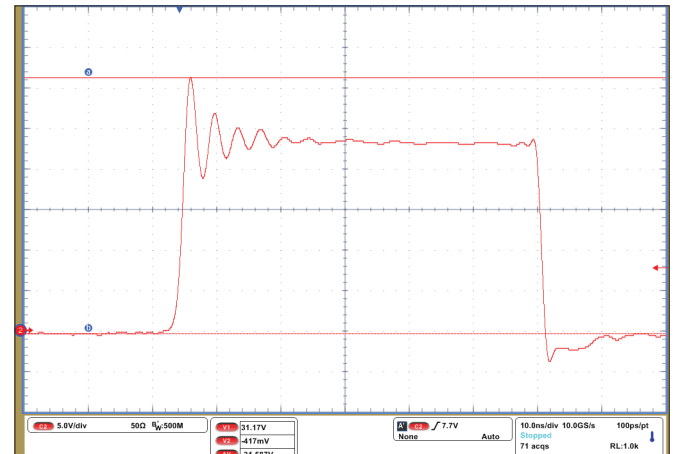


Figure 4: Typical Switch node voltage for a 24V to 1.2V/20A (1 MHz) Buck converter

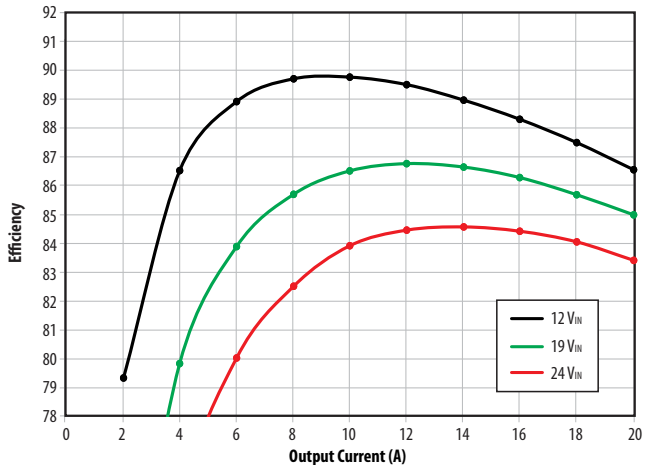
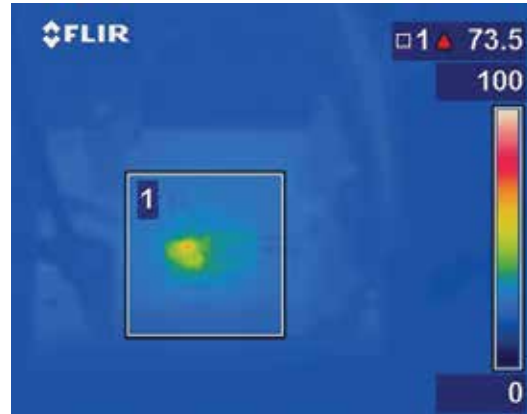


Figure 5: Typical efficiency curves for 24V, 19V and 12V input including controller and LDO losses

## THERMAL CONSIDERATIONS

The EPC9101 demonstration board thermal images for steady state full load operation are shown in Figure 6. The EPC9101 is intended for bench evaluation with low ambient temperature and forced air cooling for higher currents. Care must be taken to not exceed the absolute maximum die temperature of 125°C and stay within the constraints of the other components within the circuit.

NOTE. The EPC9101 demonstration board does not have any current or thermal protection on board.



12 V<sub>IN</sub>, 20 A<sub>OUT</sub>, 200LFM

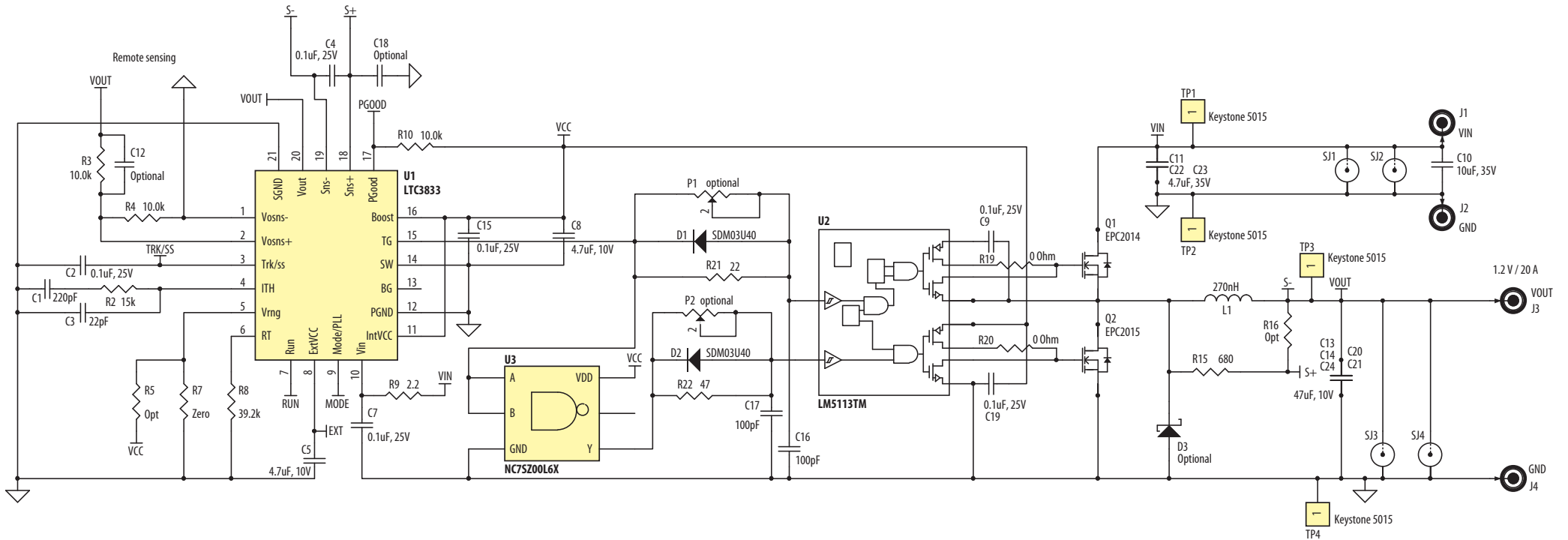
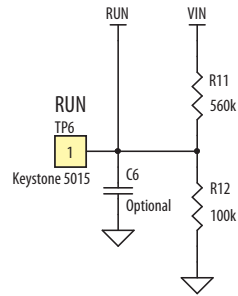
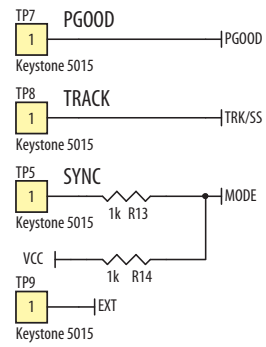


24 V<sub>IN</sub>, 20 A<sub>OUT</sub>, 200LFM

Figure 6: Thermal images of EPC9101 under full load conditions

**Table 2 : Bill of Material**

| Item | Qty | Reference                                   | Part Description                | Manufacturer / Part #              |
|------|-----|---|---------------------------------|------------------------------------|
| 1    | 1   | C1  | Capacitor, 220pF, 5%, 50V, NP0  | Murata, GRM1885C1H221JA01D         |
| 2    | 1   | C3  | Capacitor, 22pF, 5%, 50V, NP0   | Murata, GRM1885C1H220JA01D         |
| 3    | 6   | C2, C4, C7, C9, C15, C19                    | Capacitor, 0.1uF, 10%, 25V, X5R | TDK, C1005X5R1E104K                |
| 4    | 2   | C5, C8                                      | Capacitor, 4.7uF, 10%, 10V, X5R | TDK, C1608X5R1A475K                |
| 5    | 1   | C10   | Capacitor, 10uF, 20%, 35V, X5R  | Taiyo Yuden, GMK325BJ106KN         |
| 6    | 2   | C11, C22, C23                               | Capacitor, 4.7uF, 10%, 35V, X7R | TDK, C2012X6S1V475K125AB           |
| 7    | 5   | C13, C14, C20, C21, C24                     | Capacitor, 47uF, 20%, 10V, X5R  | TDK, C2012X5R1A476M                |
| 8    | 2   | C16, C17                                    | Capacitor, 100pF, 5%, 50V, NP0  | Kemet, C0402C101K5GACTU            |
| 9    | 3   | D1, D2, D4                                  | Schottky Diode, 30V             | Diodes Inc., SDM03U40-7            |
| 10   | 4   | J1, J2, J3, J4                              | Banana Jack                     | Keystone, 575-4                    |
| 11   | 1   | L1  | Inductor, 270nH                 | Coilcraft, SLC1175-271ME           |
| 12   | 1   | Q1  | eGaN® FET                       | EPC, EPC2014                       |
| 13   | 1   | Q2  | eGaN® FET                       | EPC, EPC2015                       |
| 14   | 1   | R2  | Resistor, 15.0K, 1%, 1/8W       | Stackpole, RMCF0603FT15K0          |
| 15   | 3   | R3, R4, R10                                 | Resistor, 10.0K, 1%, 1/10W      | Stackpole, RMCF0603FT10K0          |
| 16   | 3   | R7, R19, R20                                | Resistor, 0 Ohm, 1/16W          | Stackpole, RMCF0402ZT0R00          |
| 17   | 1   | R8  | Resistor, 39.2K, 1%, 1/8W       | Stackpole, RMCF0603FT39K2          |
| 18   | 1   | R9  | Resistor, 2.2 Ohm, 5%, 1/16W    | Yageo, RC0402FR-072R2L             |
| 19   | 1   | R11   | Resistor, 560K, 1%, 1/8W        | Stackpole, RMCF0603FT560K          |
| 20   | 1   | R12   | Resistor, 100K, 1%, 1/8W        | Stackpole, RMCF0603FT100K          |
| 21   | 2   | R13, R14                                    | Resistor, 1.00K, 5%, 1/10W      | Rohm, MCR03EZPJ102                 |
| 22   | 1   | R15   | Resistor, 680 Ohm, 5%, 1/8W     | Stackpole, RMCF0603FT680R          |
| 23   | 1   | R21   | Resistor, 22 Ohm, 5%, 1/8W      | Stackpole, RMCF0603JT22R0          |
| 24   | 1   | R22   | Resistor, 47 Ohm, 5%, 1/8W      | Stackpole, RMCF0603JT47R0          |
| 25   | 9   | TP1, TP2, TP3, TP4, TP5, TP6, TP7, TP8, TP9 | Measurement Point               | Keystone Elect, 5015               |
| 26   | 1   | U1  | I.C., Buck Regulator            | Linear Technology, LTC3833EUDC#PBF |
| 27   | 1   | U2  | I.C., Gate driver               | Texas Instruments, LM5113          |
| 28   | 1   | U3  | I.C., Logic                     | Fairchild, NC7SZ00L6X              |
| 29   | 4   |   | Nylon Stand-offs                | Keystone, 8834                     |
| 30   | 0   | R5, R16                                     | Optional Resistors              |                                    |
| 31   | 0   | C6, C12, C18                                | Optional Capacitors             |                                    |
| 32   | 0   | D3  | Optional Diode                  |                                    |
| 33   | 0   | P1, P2                                      | Potentiometer, 500 Ohm, 0.25W   | Murata, PV37Y501C01B00             |
| 34   | 0   | SJ1, SJ2, SJ3, SJ4                          | Optional SMA Connectors         |                                    |



**Demonstration Board – EPC9101 Schematic**  
Rev. 2.0

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